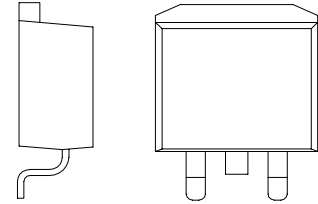
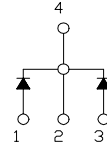


SBD Type : TCH10A15

OUTLINE DRAWING

FEATURES

- *SQUARE-PAK TO-263AB(SMD)
- Packaged in 24mm Tape and Reel
- *Dual Diodes – Cathode Common
- *Low Forward Voltage Drop
- *High Surge Capability
- *Tj=150 °C operation



Maximum Ratings

Approx Net Weight: 1.4g

Rating	Symbol	TCH10A15			Unit
Repetitive Peak Reverse Voltage	V_{RRM}	150			V
Average Rectified Output Current	I_O	10	$T_c=121^\circ\text{C}$	50 Hz Full Sine Wave Resistive Load	A
RMS Forward Current	$I_{F(RMS)}$	11.1			A
Surge Forward Current	I_{FSM}	130	50Hz Full Sine Wave ,1cycle Non-repetitive		A
Operating JunctionTemperature Range	T_{jw}	-40 to +150			°C
Storage Temperature Range	T_{stg}	-40 to +150			°C

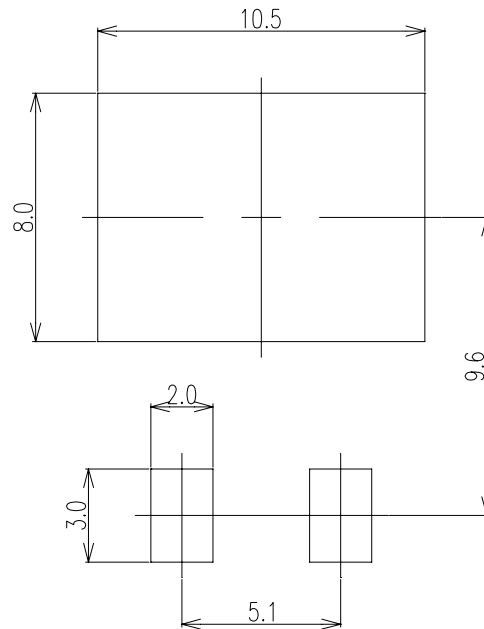
Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	I_{RM}	$T_j= 25^\circ\text{C}$, $V_{RM}= V_{RRM}$ per arm	-	-	1	mA
Peak Forward Voltage	V_{FM}	$T_j= 25^\circ\text{C}$, $I_{FM}= 5\text{ A}$ per arm	-	-	0.88	V
Thermal Resistance (Junction to Case)	$R_{th(j-c)}$	Junction to Case	-	-	3	°C /W

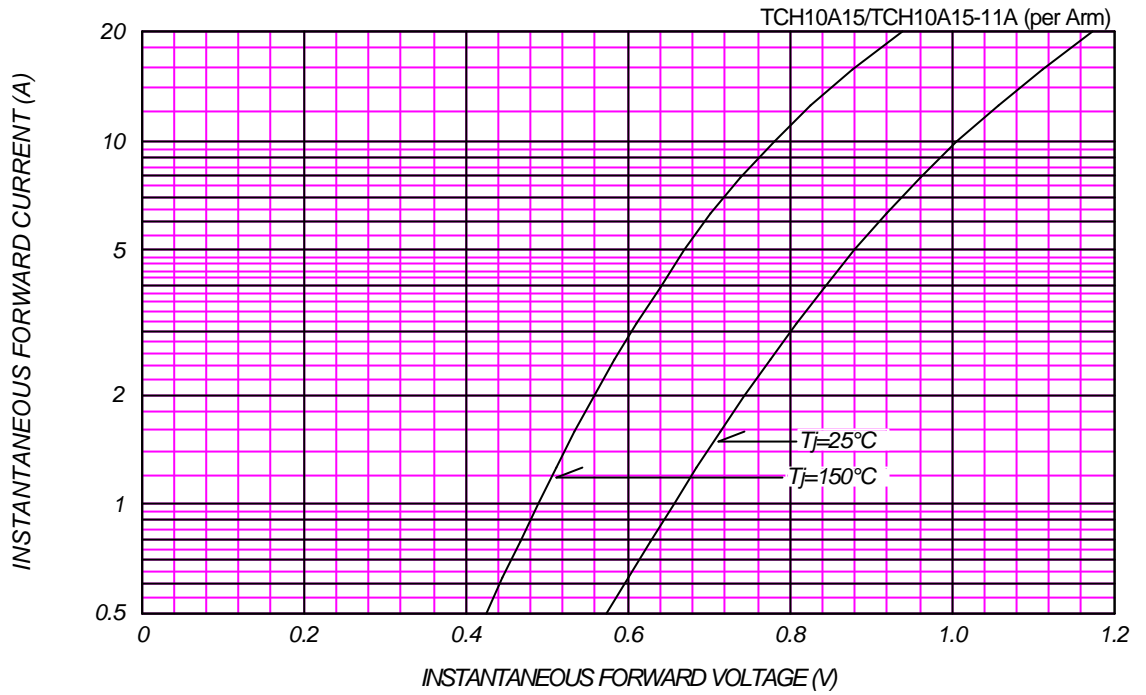
C_T_ OUTLINE DRAWING (Dimensions in mm)



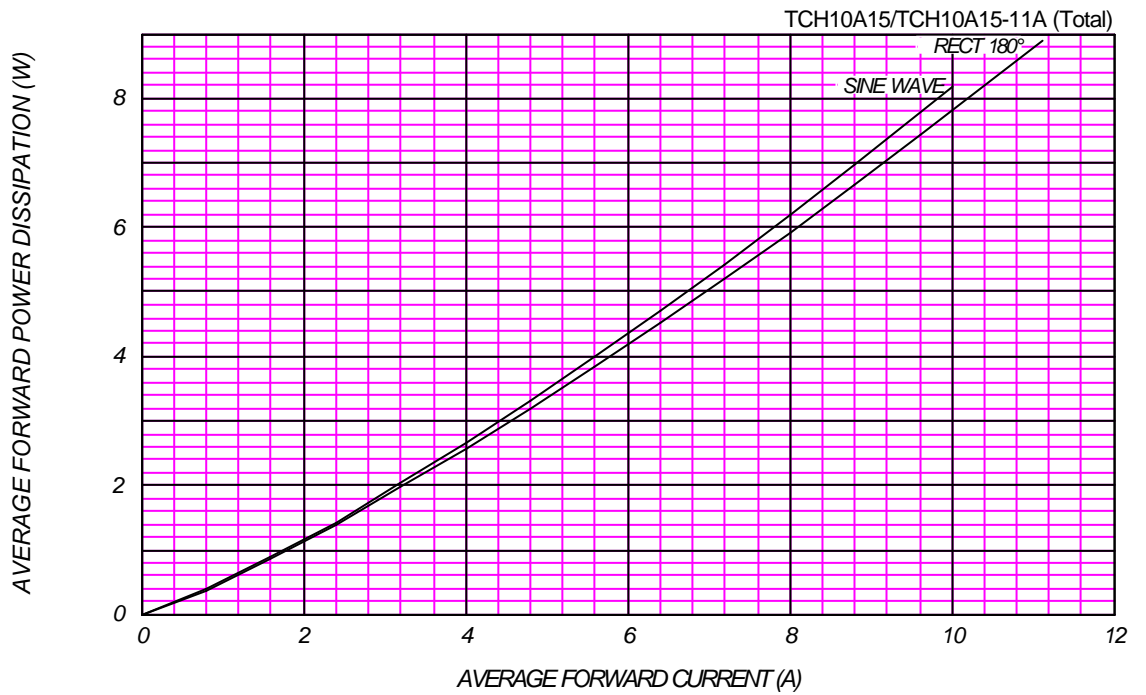
SOLDERING PAD



FORWARD CURRENT VS. VOLTAGE



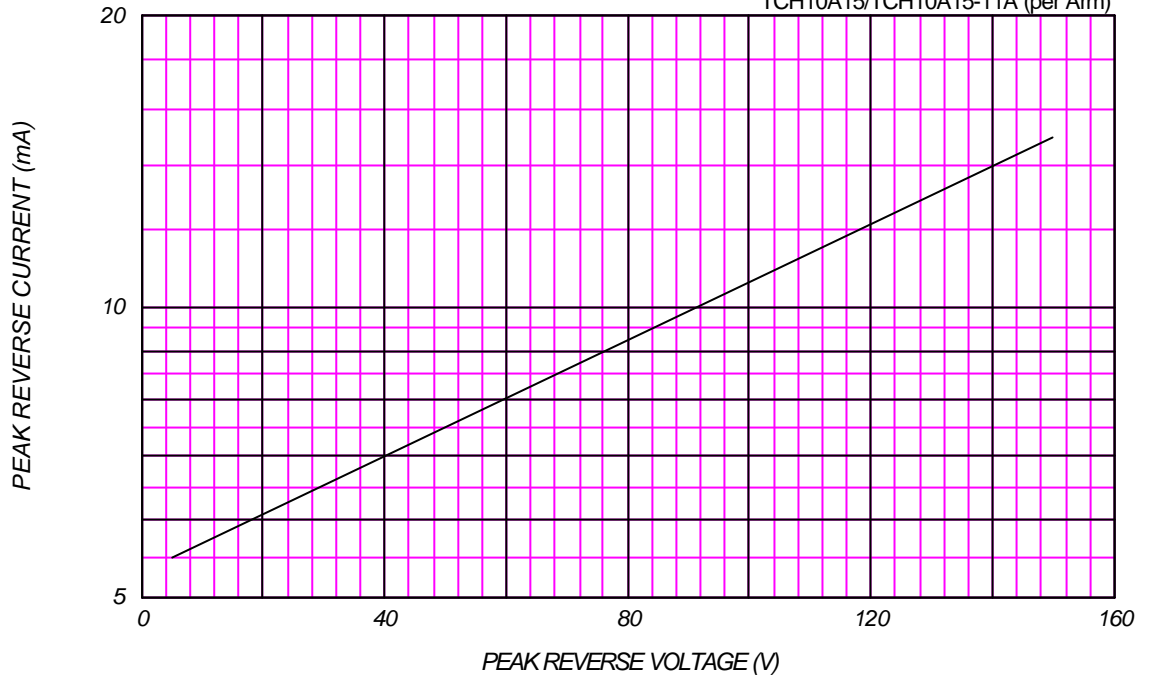
AVERAGE FORWARD POWER DISSIPATION



PEAK REVERSE CURRENT VS. PEAK REVERSE VOLTAGE

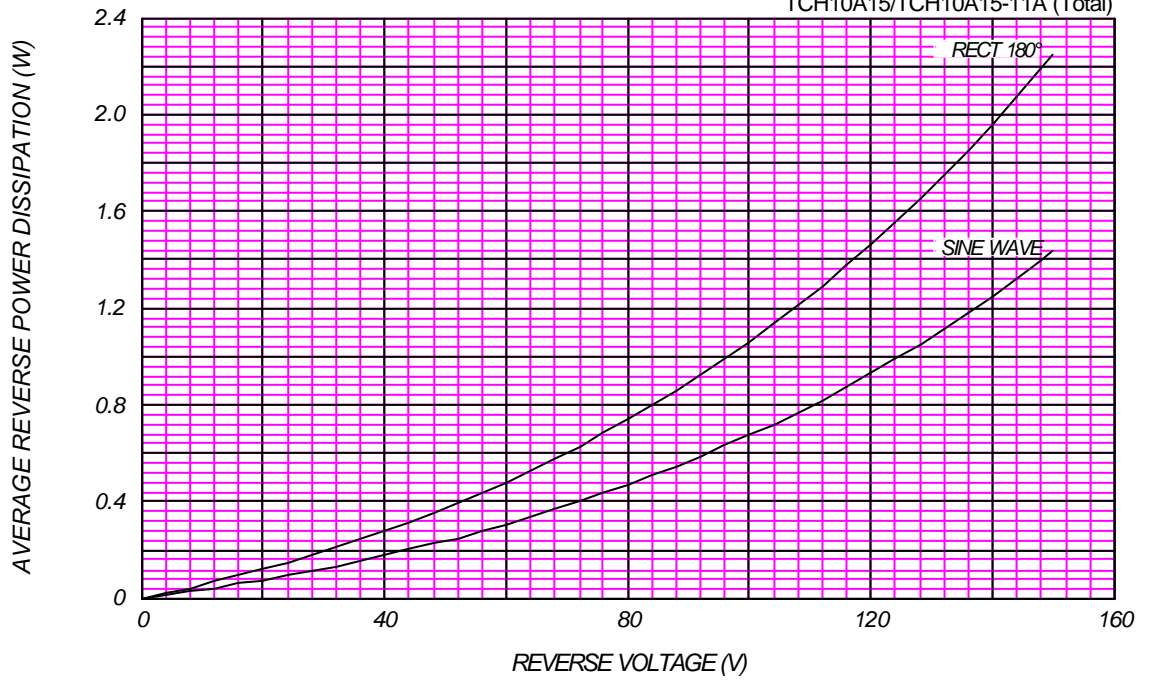
T_j = 150 °C

TCH10A15/TCH10A15-11A (per Arm)



AVERAGE REVERSE POWER DISSIPATION

TCH10A15/TCH10A15-11A (Total)

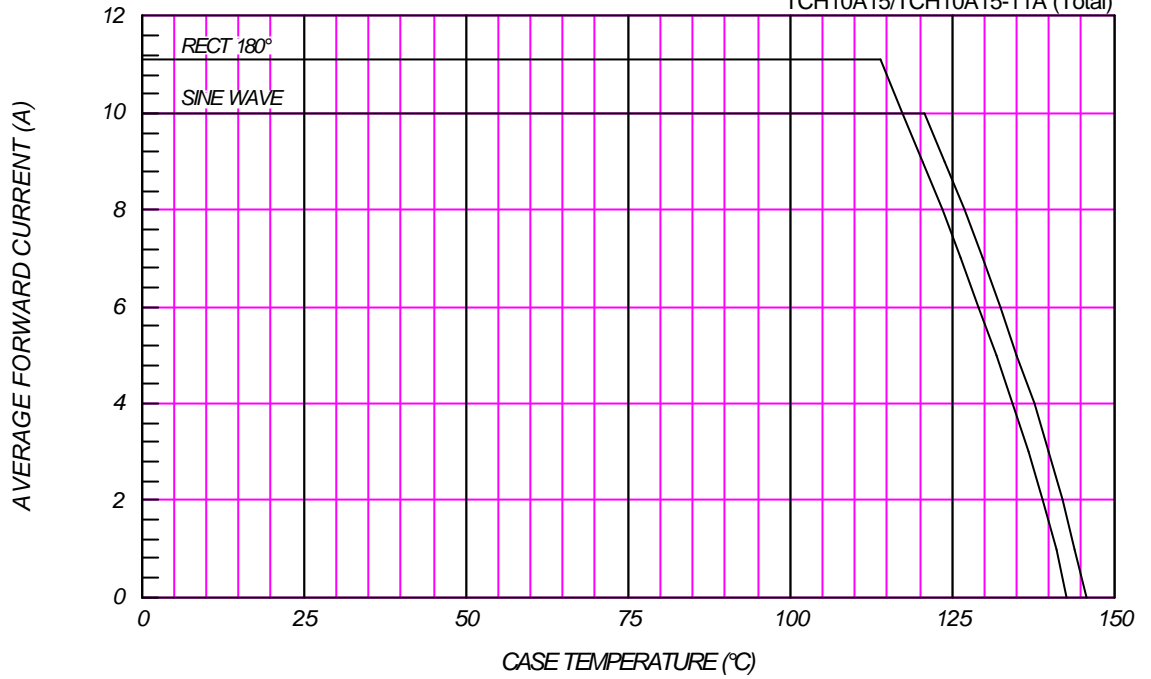




AVERAGE FORWARD CURRENT VS. CASE TEMPERATURE

$V_{RM} = 150V$

TCH10A15/TCH10A15-11A (Total)



SURGE CURRENT RATINGS

$f = 50Hz$, Sine Wave, Non-Repetitive, No Load

TCH10A15/TCH10A15-11A

